

SGM4915 Dual 145mW Headphone Amplifier with Active Low Shutdown Mode

GENERAL DESCRIPTION

The SGM4915 is a dual audio power amplifier capable of delivering 145mW per channel of continuous average power with less than 0.1% distortion (THD) when it drives a 16Ω speaker from a 5.0V power supply. It is designed to maximize audio performance in portable applications such as mobile phone. The portable application requires audio power amplifier has minimum of external components and can operate from a single 2.5V to 5.5V power supply.

SGM4915 features an externally controlled, active-low, micropower consumption shutdown mode, as well as an internal thermal shutdown protection mechanism.

SGM4915 does not require bootstrap capacitors or snubber networks. It is optimally suited for low-power portable systems.

For maximum flexibility, the SGM4915 provides an externally controlled gain (with resistors), as well as an externally controlled turn-on time (with the bypass capacitor).

The SGM4915 is available in Green TDFN-2×2-8L package. It operates over an ambient temperature range of -40°C to +85°C.

FEATURES

- Active-Low Shutdown Mode
- 145mW into 16Ω Load from 5V Power Supply at THD+N = 0.1% Typical (per Channel)
- 85mW into 32Ω Load from 5V Power Supply at THD+N = 0.1% Typical (per Channel)
- Unity Gain Stable
- Shutdown Current: 0.02µA (TYP)
- 2.5V to 5.5V Operation
- Shutdown Pin is Compatible with 1.8V Logic
- Click and Pop Reduction Circuitry
- -40°C to +85°C Operating Temperature Range
- Green TDFN-2×2-8L Package

APPLICATIONS

Portable Systems
Headphone Amplifier
Microphone Preamplifier
Notebook Computers
Mobile Phone
PDAs
GPS



PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION	
SGM4915	TDFN-2×2-8L	-40°C to +85°C	SGM4915YDE8G/TR	4915 XXXX	Tape and Reel, 3000	

MARKING INFORMATION

NOTE: XXXX = Date Code.

XXXX

Date Code - Week

Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	6V
Input Voltage	$0.3V \text{ to } (V_{CC}) + 0.3V$
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	2000V
MM	200V

RECOMMENDED OPERATING CONDITIONS

Supply Voltage Range	2.5V to 5.5V
Operating Temperature Range	40°C to +85°C

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

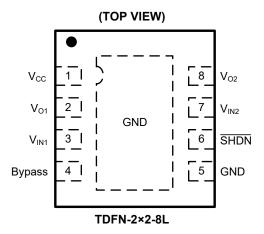
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATION



PIN DESCRIPTIONS

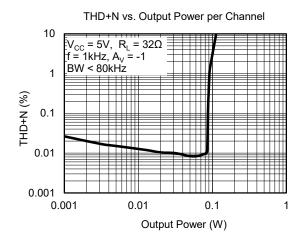
PIN	NAME	DESCRIPTION
1	C1P	Flying Capacitor Positive Terminal. Connect a 1µF ceramic capacitor from C1P to C1N.
2	PGND	Power Ground. Connect to SGND.
3	C1N	Flying Capacitor Negative Terminal. Connect a 1µF ceramic capacitor from C1P to C1N.
4	PVss	Charge-Pump Output. Connect to SV _{SS} and bypass with a 1µF ceramic capacitor to PGND.
5	SHDN	Active-Low Shutdown Input.
6 INL Left-Chan		Left-Channel Input.
7	SGND	Signal Ground. Connect to PGND.
8	INR	Right-Channel Input.
9	SV _{SS}	Amplifier Negative Supply. Connect to PV _{SS} .
10	OUTR	Right-Channel Output.
11	OUTL	Left-Channel Output.
12 V _{DD} Positive Power-Supply Input. Bypas		Positive Power-Supply Input. Bypass with a 1µF capacitor to SGND.
Exposed Paddle	_	Exposed Paddle. Can be connected to GND or left floating.

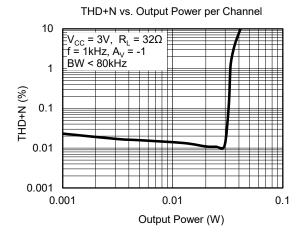
ELECTRICAL CHARACTERISTICS

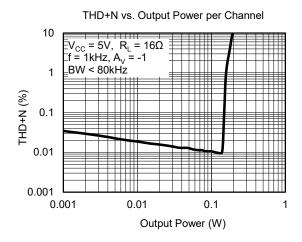
(T_A = +25°C, unless otherwise noted.)

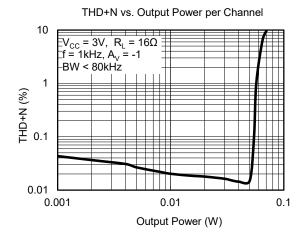
PARAMETER	SYMBOL CONDITIONS		MIN	TYP	MAX	UNITS		
					2.5		5.5	V
$V_{IN} = 0V$, $V_{SHDN} = GND$, $V_{CC} = 5.0V$				0.02	4			
Shutdown Current	I _{SD}	$V_{IN} = 0V$, $V_{SHDN} = GND$, $V_{CC} = 3.3V$				0.02		μΑ
		V _{IN} = 0V, V _{SHDN} = GND, V _{CC} = 2.6V				0.02		
		$V_{IN} = 0V$, $V_{SHDN} = V$	_{CC} = 5.0V		-50	2.5	50	mV
Output Offset Voltage	Vos	$V_{IN} = 0V$, $V_{SHDN} = V$	_{CC} = 3.3V			2.5		
		$V_{IN} = 0V, V_{SHDN} = V$	_{CC} = 2.6V			2.5		
			V _{CC} = 5.0V, No	Load		1.65	2.8	
Quiescent Power Supply Current	IQ	$V_{IN} = 0V,$ $V_{SHDN} = V_{CC}$	V_{CC} = 3.3V, No	o Load		1.50		mA
		S.I.S.IV	V _{CC} = 2.6V, No	o Load		1.40		
Shutdown Voltage Input High	V_{SDIH}				1.2			V
Shutdown Voltage Input Low	V_{SDIL}						0.4	V
		f = 1kHz THD+N = 0.1%	V _{CC} = 5.0V	$R_L = 16\Omega$		145		mW
	Po			$R_L = 32\Omega$		85		
			V _{CC} = 3.6V	$R_L = 16\Omega$		78		
Output Power (per Channel)				$R_L = 32\Omega$		44		
Cutput i ower (per orialine)			V _{CC} = 3.0V	$R_L = 16\Omega$		54		
				$R_L = 32\Omega$		31		
			V _{CC} = 2.6V	$R_L = 16\Omega$		40		
				$R_L = 32\Omega$		23		
Total Harmonic Distortion + Noise	THD+N	$P_0 = 78$ mW, $V_{CC} = f = 20$ Hz to 20kHz		,		0.1		%
Crosstalk	X _{talk}	$R_L = 32\Omega, P_O = 70$	MW , $V_{CC} = 5V$, f	= 1kHz		-85		dB
				V _{CC} = 5.0V		-67		
		$f = 217Hz, C_B = 1$	$_{LF}$, R_{L} = 32 Ω	V _{CC} = 3.6V		-67		dB
		V _{RIPPLE} = 200mVp- Input Grounded w	-p, ⁄ith 10Ω	V _{CC} = 3.0V		-65		
Davies Comple Dalastics Dati-	Done			V _{CC} = 2.6V		-64		
Power Supply Rejection Ratio	PSRR			V _{CC} = 5.0V		-75		
		f = 1kHz, C_B = 1μF, R_L = 32 Ω V_{RIPPLE} = 200mVp-p, Input Grounded with 10 Ω		V _{CC} = 3.6V		-75		
				V _{CC} = 3.0V		-74		
				V _{CC} = 2.6V		-65		

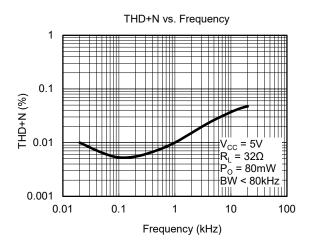
TYPICAL PERFORMANCE CHARACTERISTICS

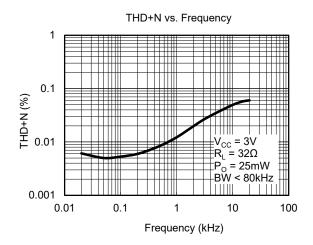




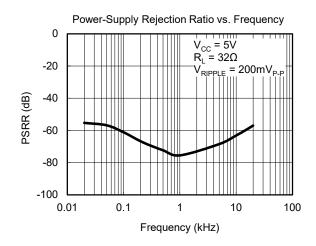


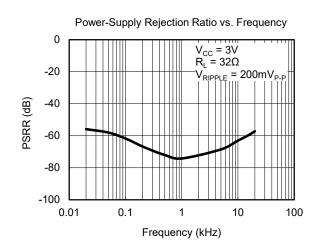


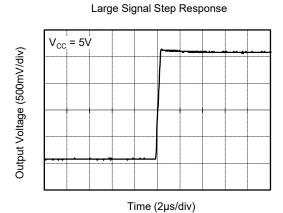




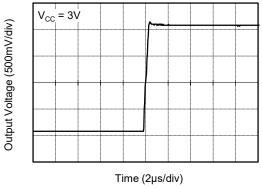
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

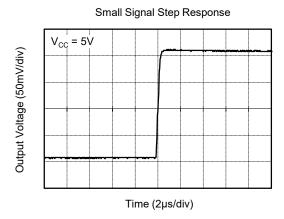


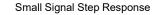


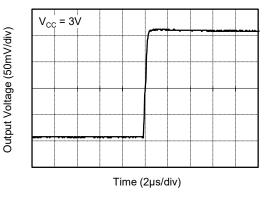




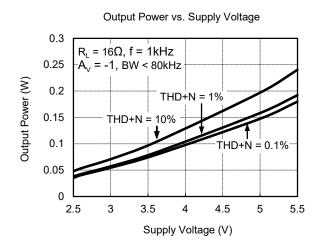


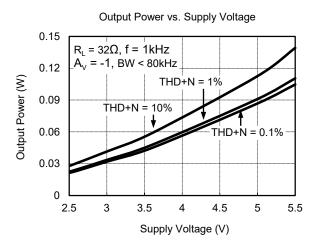


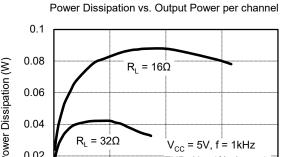


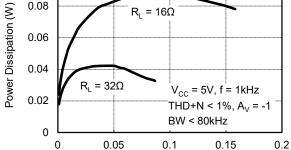


TYPICAL PERFORMANCE CHARACTERISTICS (continued)



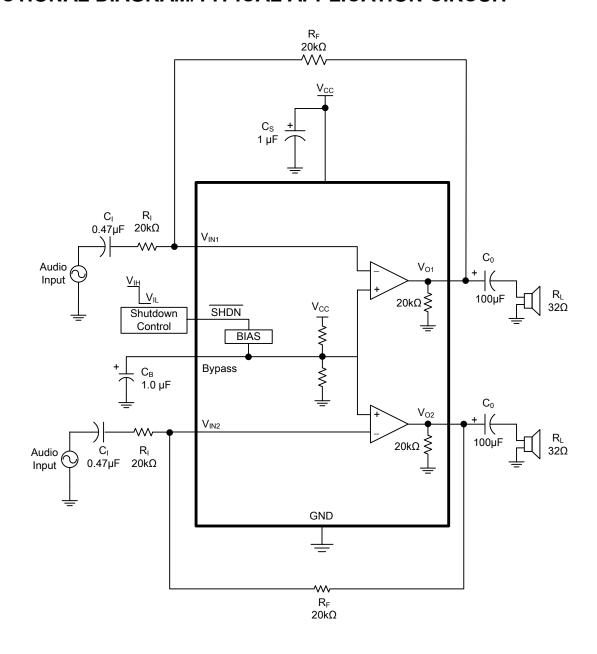






Output Power (W)

FUNCTIONAL DIAGRAM/TYPICAL APPLICATION CIRCUIT



Dual 145mW Headphone Amplifier with Active Low Shutdown Mode

SGM4915

REVISION HISTORY

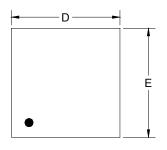
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

MAY 2011 - REV.A to REV.A.1

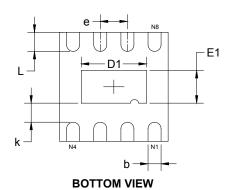
Changes from Original (MARCH 2010) to REV.A

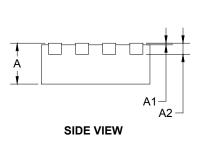


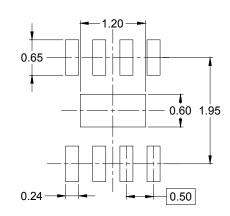
PACKAGE OUTLINE DIMENSIONS TDFN-2×2-8L



TOP VIEW





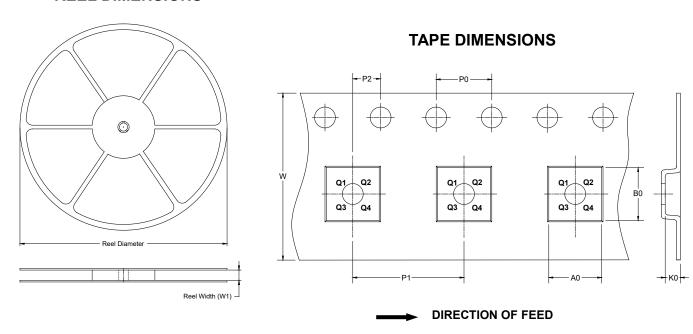


RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	_	nsions meters	Dimensions In Inches		
,	MIN	MAX	MIN	MAX	
Α	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A2	0.203	REF	0.008	REF	
D	1.900	2.100	0.075	0.083	
D1	D1 1.100		0.043	0.051	
E	1.900	2.100	0.075	0.083	
E1	E1 0.500		0.020	0.028	
k	0.200 MIN		0.008	3 MIN	
b	0.180	0.300	0.007	0.012	
е	0.500 TYP		0.020	TYP	
L	0.250	0.450	0.010	0.018	

TAPE AND REEL INFORMATION

REEL DIMENSIONS

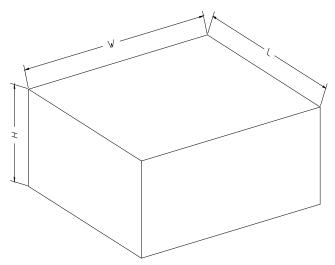


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TDFN-2×2-8L	7"	9.5	2.30	2.30	1.10	4.0	4.0	2.0	8.0	Q1

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18